

# Low Noise, High Speed Precision Operational Amplifiers

## FEATURES

- *Guaranteed*  $4.5\text{nV}/\sqrt{\text{Hz}}$  10Hz Noise
- *Guaranteed*  $3.8\text{nV}/\sqrt{\text{Hz}}$  1kHz Noise
- 0.1Hz to 10Hz Noise,  $60\text{nV}_{\text{P-P}}$  Typical
- *Guaranteed* 7 Million Min Voltage Gain,  $R_L = 2\text{k}\Omega$
- *Guaranteed* 3 Million Min Voltage Gain,  $R_L = 600\Omega$
- *Guaranteed*  $25\mu\text{V}$  Max Offset Voltage
- *Guaranteed*  $0.6\mu\text{V}/^\circ\text{C}$  Max Drift with Temperature
- *Guaranteed*  $11\text{V}/\mu\text{s}$  Min Slew Rate (LT1037)
- *Guaranteed* 117dB Min CMRR

## APPLICATIONS

- Low Noise Signal Processing
- Microvolt Accuracy Threshold Detection
- Strain Gauge Amplifiers
- Direct Coupled Audio Gain Stages
- Sine Wave Generators
- Tape Head Preamplifiers
- Microphone Preamplifiers

## DESCRIPTION

The LT<sup>®</sup>1007/LT1037 series features the lowest noise performance available to date for monolithic operational amplifiers:  $2.5\text{nV}/\sqrt{\text{Hz}}$  wideband noise (less than the noise of a  $400\Omega$  resistor),  $1/f$  corner frequency of 2Hz and  $60\text{nV}$  peak-to-peak 0.1Hz to 10Hz noise. Low noise is combined with outstanding precision and speed specifications:  $10\mu\text{V}$  offset voltage,  $0.2\mu\text{V}/^\circ\text{C}$  drift, 130dB common mode and power supply rejection, and 60MHz gain bandwidth product on the decompensated LT1037, which is stable for closed-loop gains of 5 or greater.

The voltage gain of the LT1007/LT1037 is an extremely high 20 million driving a  $2\text{k}\Omega$  load and 12 million driving a  $600\Omega$  load to  $\pm 10\text{V}$ .

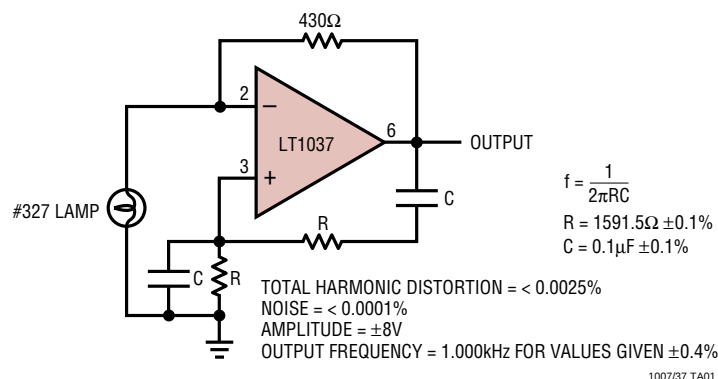
In the design, processing and testing of the device, particular attention has been paid to the optimization of the entire distribution of several key parameters. Consequently, the specifications of even the lowest cost grades (the LT1007C and the LT1037C) have been spectacularly improved compared to equivalent grades of competing amplifiers.

The sine wave generator application shown below utilizes the low noise and low distortion characteristics of the LT1037.

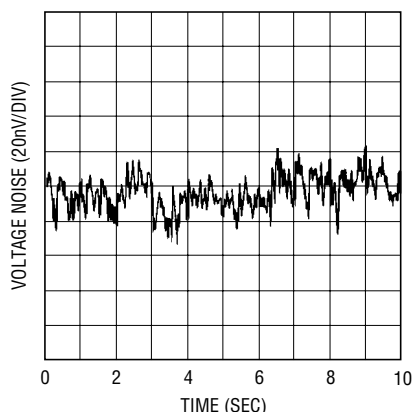
LT, LTC and LT are registered trademarks of Linear Technology Corporation.

## TYPICAL APPLICATION

Ultrapure 1kHz Sine Wave Generator



0.1Hz to 10Hz Noise



sn100737 100737fbs

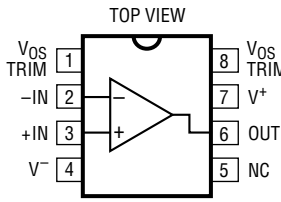
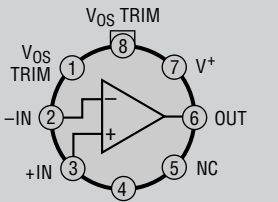
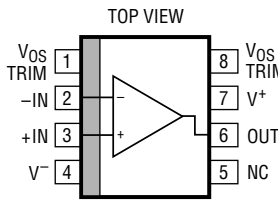
# LT1007/LT1037

## ABSOLUTE MAXIMUM RATINGS (Note 1)

Supply Voltage .....  $\pm 22\text{V}$   
 Input Voltage ..... Equal to Supply Voltage  
 Output Short-Circuit Duration ..... Indefinite  
 Differential Input Current (Note 9) .....  $\pm 25\text{mA}$   
 Storage Temperature Range .....  $-65^{\circ}\text{C}$  to  $150^{\circ}\text{C}$

Lead Temperature (Soldering, 10 sec.) .....  $300^{\circ}\text{C}$   
 Operating Temperature Range  
 LT1007/LT1037AC, C .....  $0^{\circ}\text{C}$  to  $70^{\circ}\text{C}$   
 LT1007/LT1037I .....  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$   
 LT1007/LT1037AM, M (**OBSOLETE**) .....  $-55^{\circ}\text{C}$  to  $125^{\circ}\text{C}$

## PACKAGE/ORDER INFORMATION

|                                                                                                                                                                                                                                                                                                 |                                                                                                                                                                                                                                                                                                                                                                             |                                                                                                                                                                                                                                                        |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <div><p>TOP VIEW</p><p>N8 PACKAGE<br/>8-LEAD PDIP<br/><math>T_{JMAX} = 100^{\circ}\text{C}</math>, <math>\theta_{JA} = 130^{\circ}\text{C/W}</math> (N8)</p></div>                                             | <div><p>TOP VIEW</p><p>V<sup>OS</sup> TRIM<br/>V<sup>+</sup><br/>V<sup>-</sup> (CASE)<br/>H PACKAGE<br/>8-LEAD TO-5 METAL CAN<br/><math>T_{JMAX} = 150^{\circ}\text{C}</math>, <math>\theta_{JA} = 150^{\circ}\text{C/W}</math>, <math>\theta_{JC} = 45^{\circ}\text{C/W}</math></p></div> | <div><p>TOP VIEW</p><p>S8 PACKAGE<br/>8-LEAD PLASTIC SO<br/><math>T_{JMAX} = 150^{\circ}\text{C}</math>, <math>\theta_{JA} = 190^{\circ}\text{C/W}</math></p></div> |
| ORDER PART NUMBER                                                                                                                                                                                                                                                                               | ORDER PART NUMBER                                                                                                                                                                                                                                                                                                                                                           | ORDER PART NUMBER                                                                                                                                                                                                                                      |
| LT1007ACN8    LT1037ACN8<br>LT1007CN8    LT1037CN8<br>LT1007IN8    LT1037IN8                                                                                                                                                                                                                    | LT1007ACH    LT1037ACH<br>LT1007AMH    LT1037AMH<br>LT1007CH    LT1037CH<br>LT1007MH    LT1037MH<br><b>OBSOLETE PACKAGE</b><br>Consider the N8 or S8 Package for Alternate Source                                                                                                                                                                                           | LT1007CS8    LT1037CS8<br>LT1007IS8    LT1037IS8                                                                                                                                                                                                       |
| J8 PACKAGE<br>LEAD CERP<br>$T_{JMAX} = 150^{\circ}\text{C}$ , $\theta_{JA} = 100^{\circ}\text{C/W}$ (J8)<br>LT1007ACJ8    LT1037ACJ8<br>LT1007AMJ8    LT1037AMJ8<br>LT1007CJ8    LT1037CJ8<br>LT1007MJ8    LT1037MJ8<br><b>OBSOLETE PACKAGE</b><br>Consider the N8 Package for Alternate Source |                                                                                                                                                                                                                                                                                                                                                                             | S8 PART MARKING                                                                                                                                                                                                                                        |
|                                                                                                                                                                                                                                                                                                 |                                                                                                                                                                                                                                                                                                                                                                             | 1007                      1037<br>1007I                    1037I                                                                                                                                                                                       |

Consult LTC Marketing for parts specified with wider operating temperature ranges.

## ELECTRICAL CHARACTERISTICS $V_S = \pm 15\text{V}$ , $T_A = 25^{\circ}\text{C}$ , unless otherwise noted.

| SYMBOL                                     | PARAMETER                                | CONDITIONS                                                             | LT1007AC/AM<br>LT1037AC/AM |            |            | LT1007C/I/M<br>LT1037C/I/M |            |            | UNITS                                                        |
|--------------------------------------------|------------------------------------------|------------------------------------------------------------------------|----------------------------|------------|------------|----------------------------|------------|------------|--------------------------------------------------------------|
|                                            |                                          |                                                                        | MIN                        | TYP        | MAX        | MIN                        | TYP        | MAX        |                                                              |
| $V_{OS}$                                   | Input Offset Voltage                     | (Note 2)                                                               |                            | 10         | 25         |                            | 20         | 60         | $\mu\text{V}$                                                |
| $\frac{\Delta V_{OS}}{\Delta \text{Time}}$ | Long Term Input Offset Voltage Stability | (Notes 3, 4)                                                           |                            | 0.2        | 1.0        |                            | 0.2        | 1.0        | $\mu\text{V/Mo}$                                             |
| $I_{OS}$                                   | Input Offset Current                     |                                                                        |                            | 7          | 30         |                            | 12         | 50         | nA                                                           |
| $I_B$                                      | Input Bias Current                       |                                                                        |                            | $\pm 10$   | $\pm 35$   |                            | $\pm 15$   | $\pm 55$   | nA                                                           |
| $e_n$                                      | Input Noise Voltage                      | 0.1Hz to 10Hz (Notes 4, 6)                                             |                            | 0.06       | 0.13       |                            | 0.06       | 0.13       | $\mu\text{V}_{p-p}$                                          |
|                                            | Input Noise Voltage Density              | $f_0 = 10\text{Hz}$ (Notes 4, 5)<br>$f_0 = 1000\text{Hz}$ (Note 4)     |                            | 2.8<br>2.5 | 4.5<br>3.8 |                            | 2.8<br>2.5 | 4.5<br>3.8 | $\text{nV}/\sqrt{\text{Hz}}$<br>$\text{nV}/\sqrt{\text{Hz}}$ |
| $i_n$                                      | Input Noise Current Density              | $f_0 = 10\text{Hz}$ (Notes 4, 7)<br>$f_0 = 1000\text{Hz}$ (Notes 4, 7) |                            | 1.5<br>0.4 | 4.0<br>0.6 |                            | 1.5<br>0.4 | 4.0<br>0.6 | $\text{pA}/\sqrt{\text{Hz}}$<br>$\text{pA}/\sqrt{\text{Hz}}$ |

sn100737 100737fbs

**ELECTRICAL CHARACTERISTICS**  $V_S = \pm 15V$ ,  $T_A = 25^\circ C$ , unless otherwise noted.

| SYMBOL    | PARAMETER                     | CONDITIONS                                            | LT1007AC/AM<br>LT1037AC/AM |            |     | LT1007C/I/M<br>LT1037C/I/M |            |     | UNITS     |
|-----------|-------------------------------|-------------------------------------------------------|----------------------------|------------|-----|----------------------------|------------|-----|-----------|
|           |                               |                                                       | MIN                        | TYP        | MAX | MIN                        | TYP        | MAX |           |
|           | Input Resistance, Common Mode |                                                       | 7                          |            |     | 5                          |            |     | $G\Omega$ |
|           | Input Voltage Range           |                                                       | $\pm 11.0$                 | $\pm 12.5$ |     | $\pm 11.0$                 | $\pm 12.5$ |     | V         |
| CMRR      | Common Mode Rejection Ratio   | $V_{CM} = \pm 11V$                                    | 117                        | 130        |     | 110                        | 126        |     | dB        |
| PSRR      | Power Supply Rejection Ratio  | $V_S = \pm 4V$ to $\pm 18V$                           | 110                        | 130        |     | 106                        | 126        |     | dB        |
| $A_{VOL}$ | Large-Signal Voltage Gain     | $R_L \geq 2k$ , $V_O = \pm 12V$                       | 7.0                        | 20.0       |     | 5.0                        | 20.0       |     | $V/\mu V$ |
|           |                               | $R_L \geq 1k$ , $V_O = \pm 10V$                       | 5.0                        | 16.0       |     | 3.5                        | 16.0       |     | $V/\mu V$ |
|           |                               | $R_L \geq 600\Omega$ , $V_O = \pm 10V$                | 3.0                        | 12.0       |     | 2.0                        | 12.0       |     | $V/\mu V$ |
| $V_{OUT}$ | Maximum Output Voltage Swing  | $R_L \geq 2k$                                         | $\pm 13.0$                 | $\pm 13.8$ |     | $\pm 12.5$                 | $\pm 13.5$ |     | V         |
|           |                               | $R_L \geq 600\Omega$                                  | $\pm 11.0$                 | $\pm 12.5$ |     | $\pm 10.5$                 | $\pm 12.5$ |     | V         |
| SR        | Slew Rate                     | LT1007<br>$R_L \geq 2k$                               | 1.7                        | 2.5        |     | 1.7                        | 2.5        |     | $V/\mu s$ |
|           |                               | LT1037<br>$A_{VCL} \geq 5$                            | 11                         | 15         |     | 11                         | 15         |     | $V/\mu s$ |
| GBW       | Gain Bandwidth Product        | LT1007<br>$f_0 = 100kHz$ (Note 8)                     | 5.0                        | 8.0        |     | 5.0                        | 8.0        |     | MHz       |
|           |                               | LT1037<br>$f_0 = 10kHz$ (Note 8) ( $A_{VCL} \geq 5$ ) | 45                         | 60         |     | 45                         | 60         |     | MHz       |
| $Z_O$     | Open-Loop Output Resistance   | $V_O = 0V$ , $I_O = 0$                                | 70                         |            |     | 70                         |            |     | $\Omega$  |
| $P_D$     | Power Dissipation             | LT1007                                                | 80                         |            |     | 80                         |            |     | mW        |
|           |                               | LT1037                                                | 80                         |            |     | 85                         |            |     | mW        |

The ● denotes the specifications which apply over the temperature range  $0^\circ C \leq T_A \leq 70^\circ C$ ,  $V_S = \pm 15V$ , unless otherwise noted.

| SYMBOL                              | PARAMETER                    | CONDITIONS                      |   | LT1007AC<br>LT1037AC |            |     | LT1007C<br>LT1037C |            |     | UNITS            |
|-------------------------------------|------------------------------|---------------------------------|---|----------------------|------------|-----|--------------------|------------|-----|------------------|
|                                     |                              |                                 |   | MIN                  | TYP        | MAX | MIN                | TYP        | MAX |                  |
| $V_{OS}$                            | Input Offset Voltage         | (Note 2)                        | ● | 20                   |            |     | 35                 |            |     | $\mu V$          |
| $\frac{\Delta V_{OS}}{\Delta Temp}$ | Average Input Offset Drift   | (Note 10)                       | ● | 0.2                  |            |     | 0.3                |            |     | $\mu V/^\circ C$ |
| $I_{OS}$                            | Input Offset Current         |                                 | ● | 10                   |            |     | 15                 |            |     | nA               |
| $I_B$                               | Input Bias Current           |                                 | ● | $\pm 14$             |            |     | $\pm 20$           |            |     | nA               |
|                                     | Input Voltage Range          |                                 | ● | $\pm 10.5$           | $\pm 11.8$ |     | $\pm 10.5$         | $\pm 11.8$ |     | V                |
| CMRR                                | Common Mode Rejection Ratio  | $V_{CM} = \pm 10.5V$            | ● | 114                  | 126        |     | 106                | 120        |     | dB               |
| PSRR                                | Power Supply Rejection Ratio | $V_S = \pm 4.5V$ to $\pm 18V$   | ● | 106                  | 126        |     | 102                | 120        |     | dB               |
| $A_{VOL}$                           | Large-Signal Voltage Gain    | $R_L \geq 2k$ , $V_O = \pm 10V$ | ● | 4.0                  | 18.0       |     | 2.5                | 18.0       |     | $V/\mu V$        |
|                                     |                              | $R_L \geq 1k$ , $V_O = \pm 10V$ | ● | 2.5                  | 14.0       |     | 2.0                | 14.0       |     | $V/\mu V$        |
| $V_{OUT}$                           | Maximum Output Voltage Swing | $R_L \geq 2k$                   | ● | $\pm 12.5$           | $\pm 13.6$ |     | $\pm 12.0$         | $\pm 13.6$ |     | V                |
| $P_D$                               | Power Dissipation            |                                 | ● | 90                   |            |     | 90                 |            |     | mW               |

## ELECTRICAL CHARACTERISTICS

The ● denotes the specifications which apply over the temperature range  $-40^{\circ}\text{C} \leq T_A \leq 85^{\circ}\text{C}$ ,  $V_S = \pm 15\text{V}$ , unless otherwise noted.

| SYMBOL                                     | PARAMETER                    | CONDITIONS                                    |   | LT1007I/LT1037I |            |          | UNITS                          |
|--------------------------------------------|------------------------------|-----------------------------------------------|---|-----------------|------------|----------|--------------------------------|
|                                            |                              |                                               |   | MIN             | TYP        | MAX      |                                |
| $V_{OS}$                                   | Input Offset Voltage         | (Note 2)                                      | ● |                 | 40         | 125      | $\mu\text{V}$                  |
| $\frac{\Delta V_{OS}}{\Delta \text{Temp}}$ | Average Input Offset Drift   | (Note 10)                                     | ● |                 | 0.3        | 1.0      | $\mu\text{V}/^{\circ}\text{C}$ |
| $I_{OS}$                                   | Input Offset Current         |                                               | ● |                 | 20         | 80       | nA                             |
| $I_B$                                      | Input Bias Current           |                                               | ● |                 | $\pm 25$   | $\pm 90$ | nA                             |
|                                            | Input Voltage Range          |                                               | ● | $\pm 10$        | $\pm 11.7$ |          | V                              |
| CMRR                                       | Common Mode Rejection Ratio  | $V_{CM} = \pm 10.5\text{V}$                   | ● | 105             | 120        |          | dB                             |
| PSRR                                       | Power Supply Rejection Ratio | $V_S = \pm 4.5\text{V}$ to $\pm 18\text{V}$   | ● | 101             | 120        |          | dB                             |
| $A_{VOL}$                                  | Large-Signal Voltage Gain    | $R_L \geq 2\text{k}$ , $V_O = \pm 10\text{V}$ | ● | 2.0             | 15.0       |          | $\text{V}/\mu\text{V}$         |
|                                            |                              | $R_L \geq 1\text{k}$ , $V_O = \pm 10\text{V}$ | ● | 1.5             | 12.0       |          | $\text{V}/\mu\text{V}$         |
| $V_{OUT}$                                  | Maximum Output Voltage Swing | $R_L \geq 2\text{k}$                          | ● | $\pm 12.0$      | $\pm 13.6$ |          | V                              |
| $P_D$                                      | Power Dissipation            |                                               | ● |                 | 95         | 165      | mW                             |

The ● denotes the specifications which apply over the temperature range  $-55^{\circ}\text{C} \leq T_A \leq 125^{\circ}\text{C}$ ,  $V_S = \pm 15\text{V}$ , unless otherwise noted.

| SYMBOL                                     | PARAMETER                    | CONDITIONS                                    |   | LT1007AM/LT1037AM |            |          | LT1007M/LT1037M |            |          | UNITS                          |
|--------------------------------------------|------------------------------|-----------------------------------------------|---|-------------------|------------|----------|-----------------|------------|----------|--------------------------------|
|                                            |                              |                                               |   | MIN               | TYP        | MAX      | MIN             | TYP        | MAX      |                                |
| $V_{OS}$                                   | Input Offset Voltage         | (Note 2)                                      | ● |                   | 25         | 60       |                 | 50         | 160      | $\mu\text{V}$                  |
| $\frac{\Delta V_{OS}}{\Delta \text{Temp}}$ | Average Input Offset Drift   | (Note 10)                                     | ● |                   | 0.2        | 0.6      |                 | 0.3        | 1.0      | $\mu\text{V}/^{\circ}\text{C}$ |
| $I_{OS}$                                   | Input Offset Current         |                                               | ● |                   | 15         | 50       |                 | 20         | 85       | nA                             |
| $I_B$                                      | Input Bias Current           |                                               | ● |                   | $\pm 20$   | $\pm 60$ |                 | $\pm 35$   | $\pm 95$ | nA                             |
|                                            | Input Voltage Range          |                                               | ● | $\pm 10.3$        | $\pm 11.5$ |          | $\pm 10.3$      | $\pm 11.5$ |          | V                              |
| CMRR                                       | Common Mode Rejection Ratio  | $V_{CM} = \pm 10.3\text{V}$                   | ● | 112               | 126        |          | 104             | 120        |          | dB                             |
| PSRR                                       | Power Supply Rejection Ratio | $V_S = \pm 4.5\text{V}$ to $\pm 18\text{V}$   | ● | 104               | 126        |          | 100             | 120        |          | dB                             |
| $A_{VOL}$                                  | Large-Signal Voltage Gain    | $R_L \geq 2\text{k}$ , $V_O = \pm 10\text{V}$ | ● | 3.0               | 14.0       |          | 2.0             | 14.0       |          | $\text{V}/\mu\text{V}$         |
|                                            |                              | $R_L \geq 1\text{k}$ , $V_O = \pm 10\text{V}$ | ● | 2.0               | 10.0       |          | 1.5             | 10.0       |          | $\text{V}/\mu\text{V}$         |
| $V_{OUT}$                                  | Maximum Output Voltage Swing | $R_L \geq 2\text{k}$                          | ● | $\pm 12.5$        | $\pm 13.5$ |          | $\pm 12.0$      | $\pm 13.5$ |          | V                              |
| $P_D$                                      | Power Dissipation            |                                               | ● |                   | 100        | 150      |                 | 100        | 170      | mW                             |

For MIL-STD components, please refer to LTC 883C data sheet for test listing and parameters.

**Note 1:** Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

**Note 2:** Input Offset Voltage measurements are performed by automatic test equipment approximately 0.5 seconds after application of power. AM and AC grades are guaranteed fully warmed up.

**Note 3:** Long Term Input Offset Voltage Stability refers to the average trend line of Offset Voltage vs Time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in  $V_{OS}$  during the first 30 days are typically  $2.5\mu\text{V}$ . Refer to typical performance curve.

**Note 4:** This parameter is tested on a sample basis only.

**Note 5:** 10Hz noise voltage density is sample tested on every lot. Devices 100% tested at 10Hz are available on request.

**Note 6:** See the test circuit and frequency response curve for 0.1Hz to 10Hz tester in the Applications Information section.

**Note 7:** See the test circuit for current noise measurement in the Applications Information section.

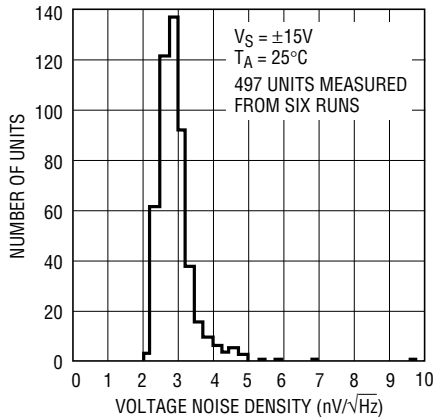
**Note 8:** This parameter is guaranteed by design and is not tested.

**Note 9:** The inputs are protected by back-to-back diodes. Current limiting resistors are not used in order to achieve low noise. If differential input voltage exceeds  $\pm 0.7\text{V}$ , the input current should be limited to 25mA.

**Note 10:** The Average Input Offset Drift performance is within the specifications unnullled or when nullled with a pot having a range of  $8\text{k}\Omega$  to  $20\text{k}\Omega$ .

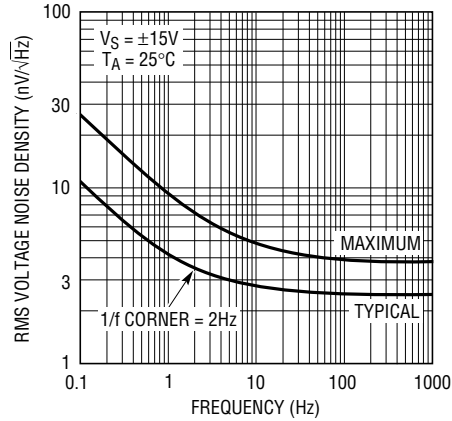
# TYPICAL PERFORMANCE CHARACTERISTICS

## 10Hz Voltage Noise Distribution



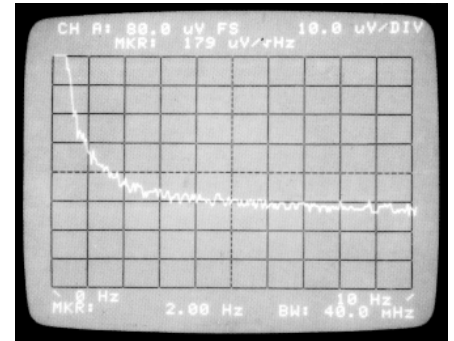
1007/37 G01

## Voltage Noise vs Frequency



1007/37 G02

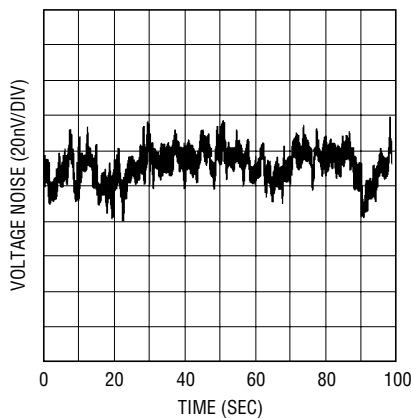
## 0.02Hz to 10Hz RMS Noise. Gain = 50,000 (Measured on HP3582 Spectrum Analyzer)



$$\text{MARKER AT 2Hz (} = 1/f \text{ CORNER)} = \frac{179 \mu\text{V}/\sqrt{\text{Hz}}}{50,000} = 3.59 \frac{\text{nV}}{\sqrt{\text{Hz}}}$$

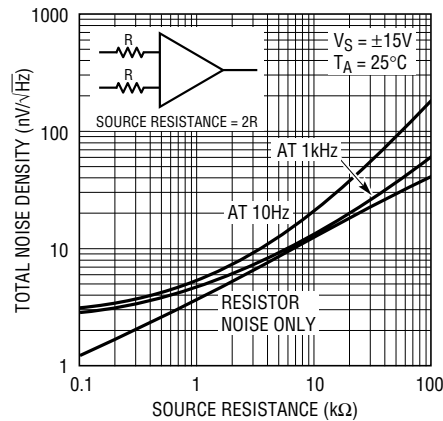
1007/37 G03

## 0.01Hz to 1Hz Peak-to-Peak Noise



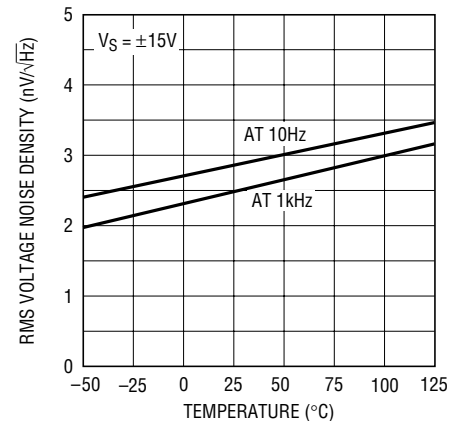
1007/37 G04

## Total Noise vs Source Resistance



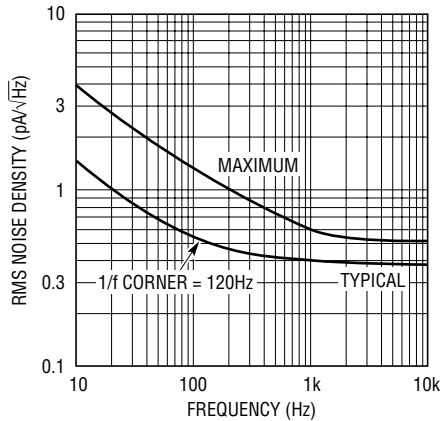
1007/37 G05

## Voltage Noise vs Temperature



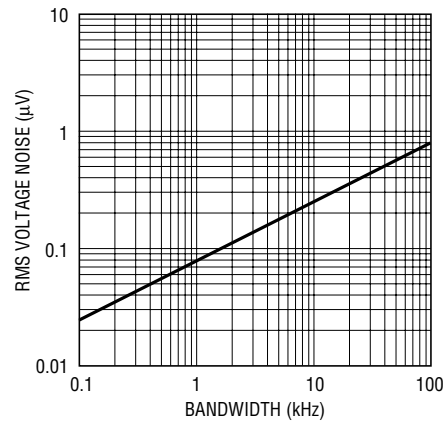
1007/37 G06

## Current Noise vs Frequency



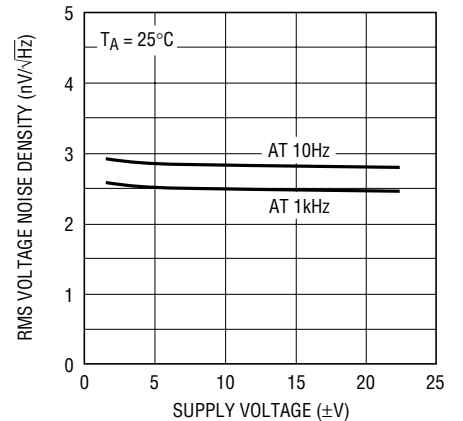
1007/37 G07

## Wideband Voltage Noise (0.1Hz to Frequency Indicated)



1007/37 G08

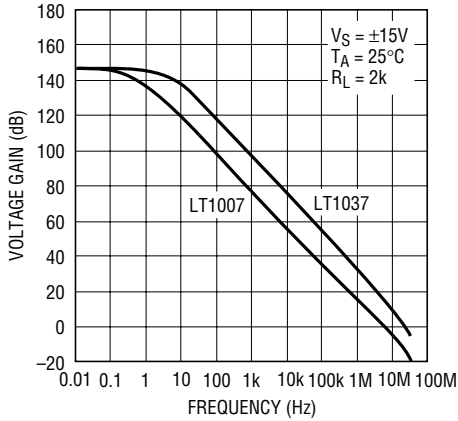
## Voltage Noise vs Supply Voltage



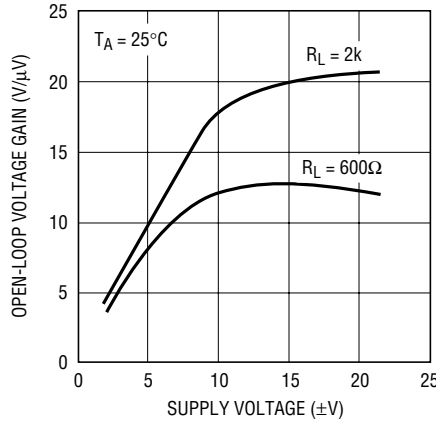
1007/37 G09

# TYPICAL PERFORMANCE CHARACTERISTICS

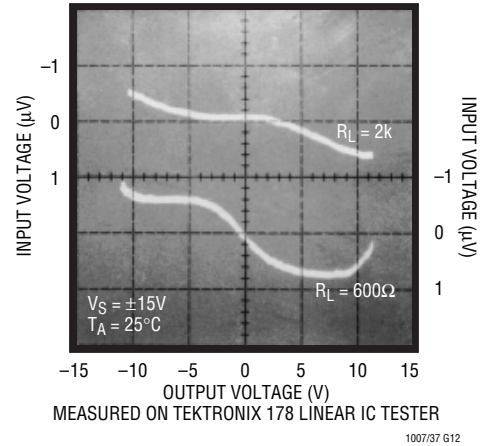
Voltage Gain vs Frequency



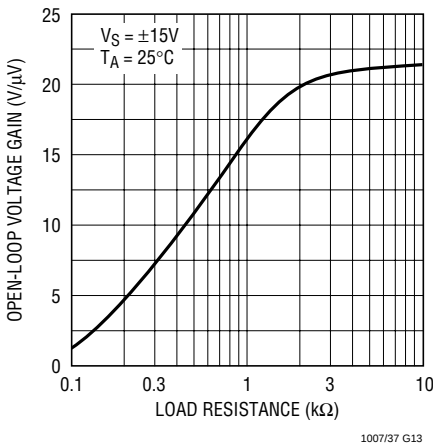
Voltage Gain vs Supply Voltage



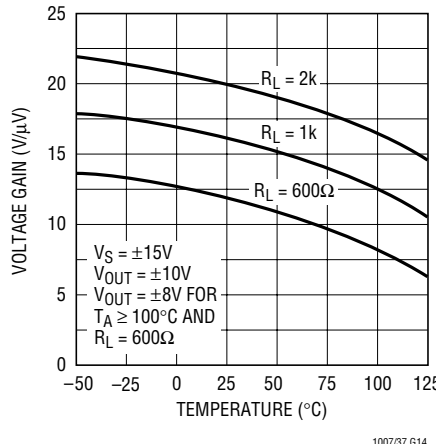
Voltage Gain,  $R_L = 2k$  and  $600\Omega$



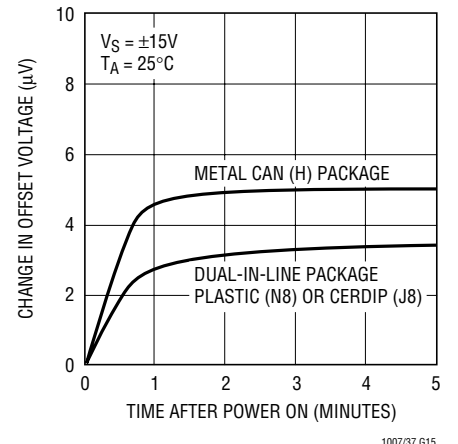
Voltage Gain vs Load Resistance



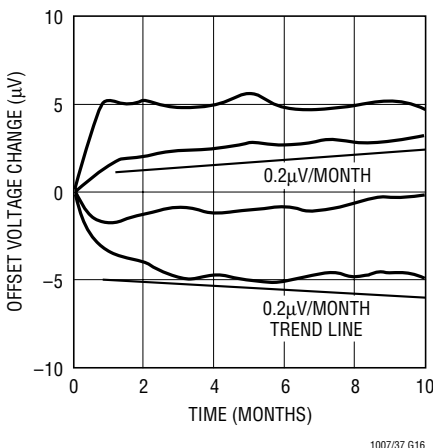
Voltage Gain vs Temperature



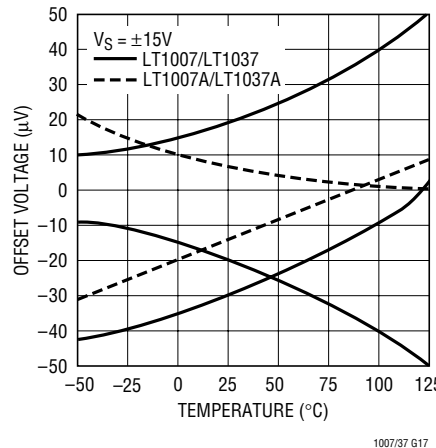
Warm-Up Drift



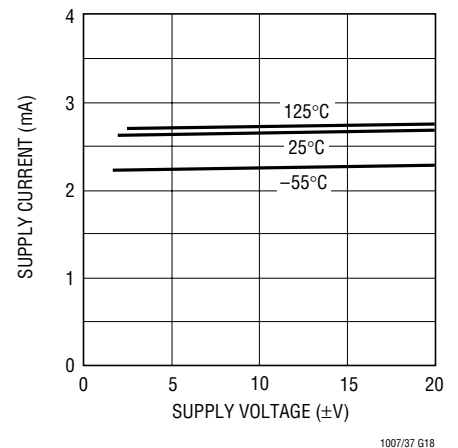
Long Term Stability of Four Representative Units



Offset Voltage Drift with Temperature of Representative Units

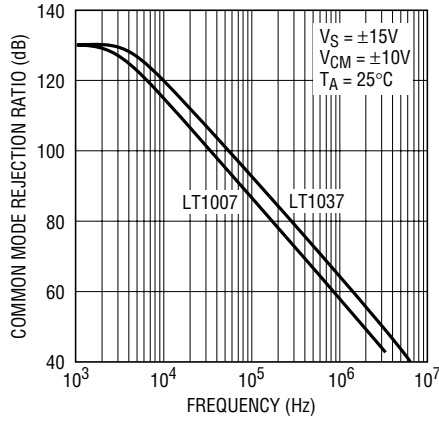


Supply Current vs Supply Voltage



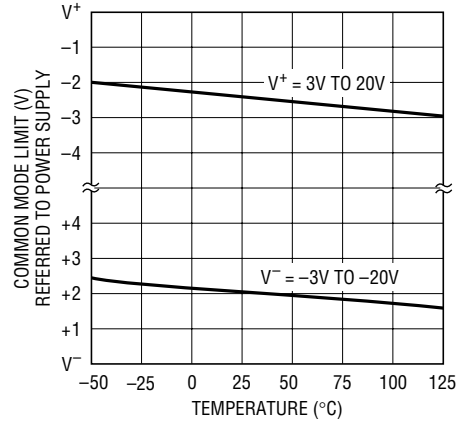
# TYPICAL PERFORMANCE CHARACTERISTICS

**Common Mode Rejection vs Frequency**



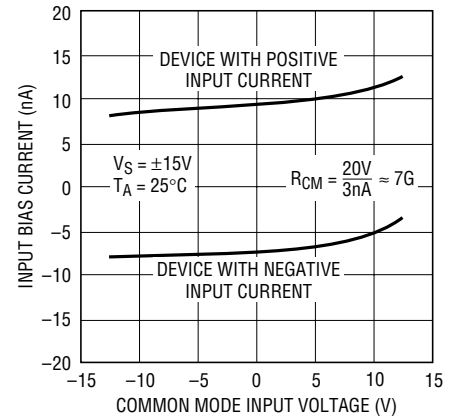
1007/37 G19

**Common Mode Limit vs Temperature**



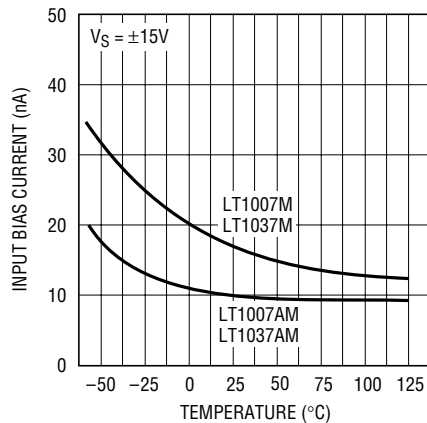
1007/37 G20

**Input Bias Current Over the Common Mode Range**



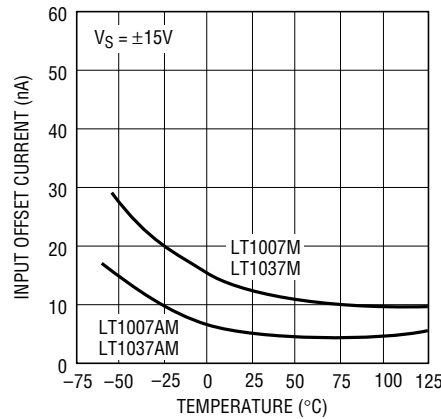
1007/37 G21

**Input Bias Current vs Temperature**



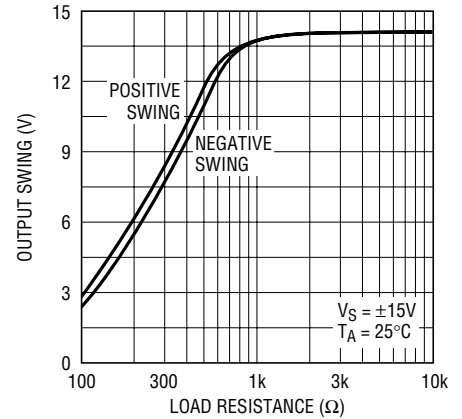
1007/37 G22

**Input Offset Current vs Temperature**



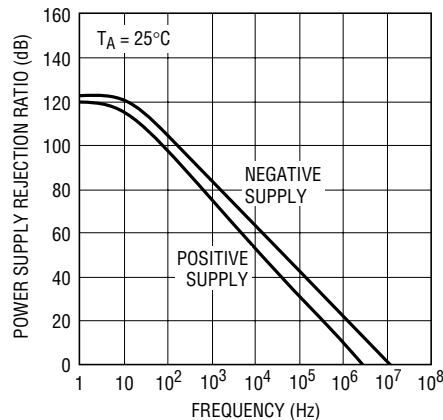
1007/37 G23

**Output Swing vs Load Resistance**



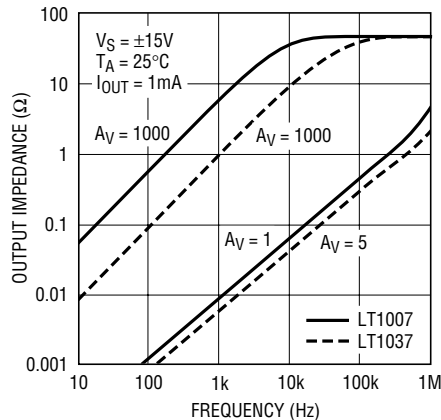
1007/37 G24

**PSRR vs Frequency**



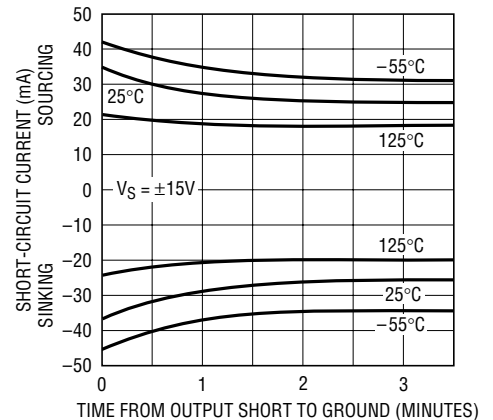
1195 G25

**Closed-Loop Output Impedance**



1007/37 G26

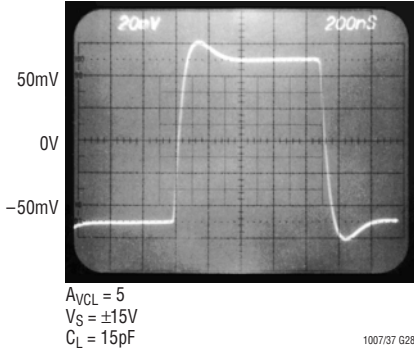
**Output Short-Circuit Current vs Time**



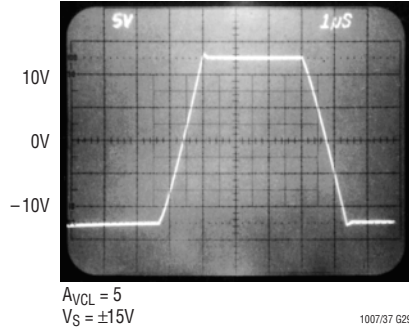
1007/37 G27

# TYPICAL PERFORMANCE CHARACTERISTICS

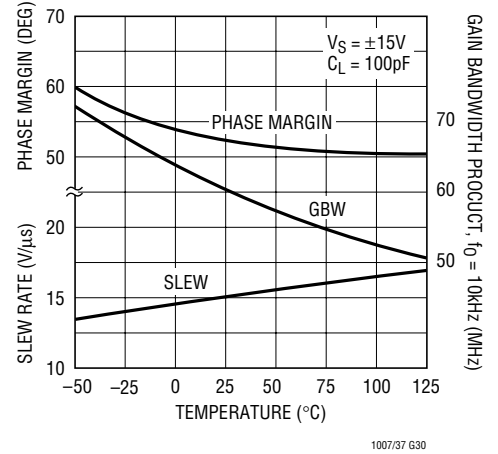
**LT1037 Small-Signal Transient Response**



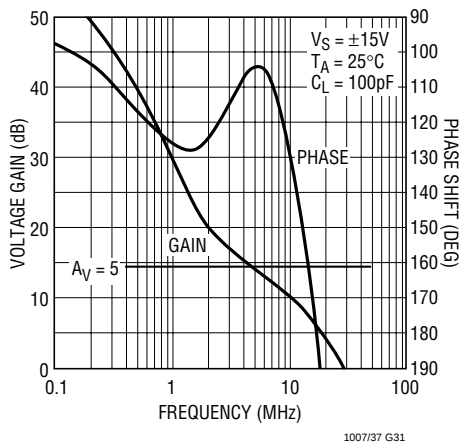
**LT1037 Large-Signal Response**



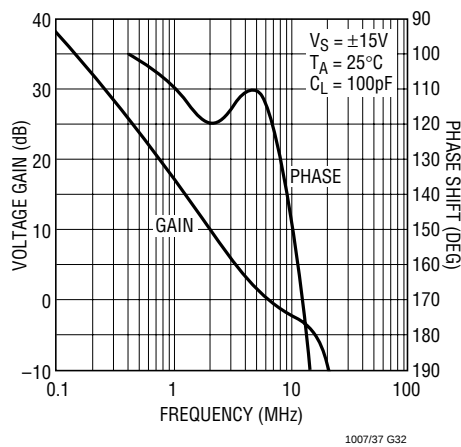
**LT1037 Phase Margin, Gain Bandwidth Product, Slew Rate vs Temperature**



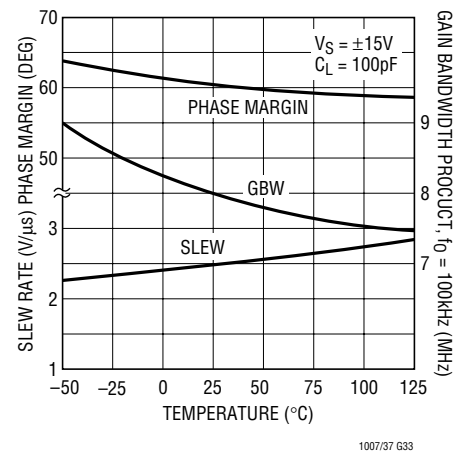
**LT1037 Gain, Phase Shift vs Frequency**



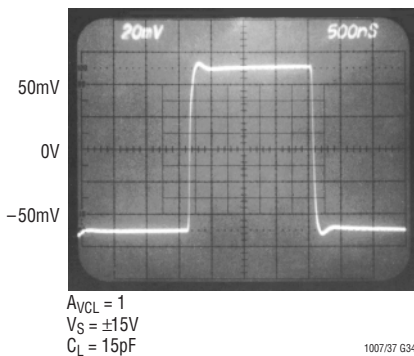
**LT1007 Gain, Phase Shift vs Frequency**



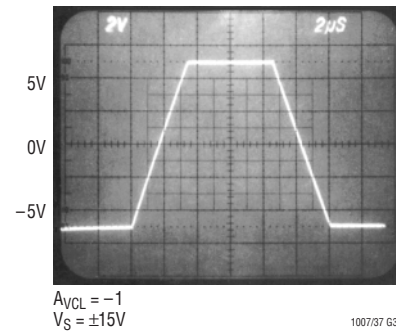
**LT1007 Phase Margin, Gain Bandwidth Product, Slew Rate vs Temperature**



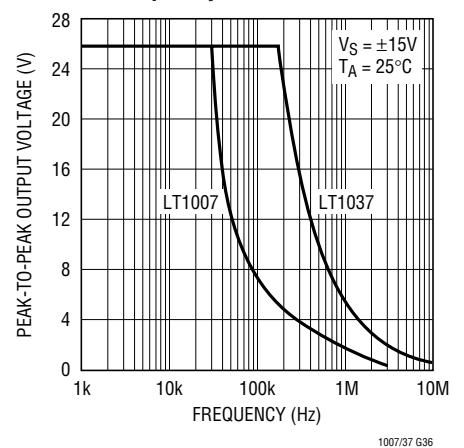
**LT1007 Small-Signal Transient Response**



**LT1007 Large-Signal Response**



**Maximum Undistorted Output vs Frequency**



## APPLICATIONS INFORMATION

### General

The LT1007/LT1037 series devices may be inserted directly into OP-07, OP-27, OP-37 and 5534 sockets with or without removal of external compensation or nulling components. In addition, the LT1007/LT1037 may be fitted to 741 sockets with the removal or modification of external nulling components.

### Offset Voltage Adjustment

The input offset voltage of the LT1007/LT1037 and its drift with temperature, are permanently trimmed at wafer testing to a low level. However, if further adjustment of  $V_{OS}$  is necessary, the use of a  $10k\Omega$  nulling potentiometer will not degrade drift with temperature. Trimming to a value other than zero creates a drift of  $(V_{OS}/300)\mu V/^{\circ}C$ , e.g., if  $V_{OS}$  is adjusted to  $300\mu V$ , the change in drift will be  $1\mu V/^{\circ}C$  (Figure 1).

The adjustment range with a  $10k\Omega$  pot is approximately  $\pm 2.5mV$ . If less adjustment range is needed, the sensitivity and resolution of the nulling can be improved by using a smaller pot in conjunction with fixed resistors. The example has an approximate null range of  $\pm 200\mu V$  (Figure 2).

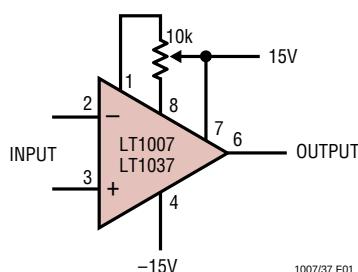


Figure 1. Standard Adjustment

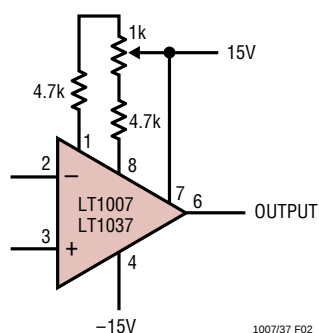


Figure 2. Improved Sensitivity Adjustment

### Offset Voltage and Drift

Thermocouple effects, caused by temperature gradients across dissimilar metals at the contacts to the input terminals, can exceed the inherent drift of the amplifier unless proper care is exercised. Air currents should be minimized, package leads should be short, the two input leads should be close together and maintained at the same temperature.

The circuit shown to measure offset voltage is also used as the burn-in configuration for the LT1007/LT1037, with the supply voltages increased to  $\pm 20V$  (Figure 3).

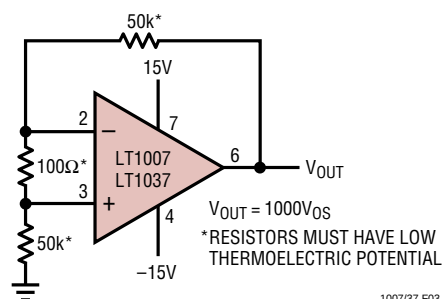


Figure 3. Test Circuit for Offset Voltage and Offset Voltage Drift with Temperature

### Unity-Gain Buffer Application (LT1007 Only)

When  $R_F \leq 100\Omega$  and the input is driven with a fast, large-signal pulse ( $>1V$ ), the output waveform will look as shown in the pulsed operation diagram (Figure 4).

During the fast feedthrough-like portion of the output, the input protection diodes effectively short the output to the input and a current, limited only by the output short-circuit protection, will be drawn by the signal generator. With  $R_F \geq 500\Omega$ , the output is capable of handling the current requirements ( $I_L \leq 20mA$  at  $10V$ ) and the amplifier stays in its active mode and a smooth transition will occur.

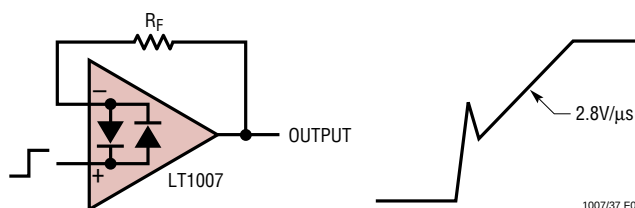


Figure 4. Pulsed Operation

sn100737 100737fbs

## APPLICATIONS INFORMATION

As with all operational amplifiers when  $R_F > 2k$ , a pole will be created with  $R_F$  and the amplifier's input capacitance, creating additional phase shift and reducing the phase margin. A small capacitor (20pF to 50pF) in parallel with  $R_F$  will eliminate this problem.

### Noise Testing

The 0.1Hz to 10Hz peak-to-peak noise of the LT1007/LT1037 is measured in the test circuit shown (Figure 5a). The frequency response of this noise tester (Figure 5b) indicates that the 0.1Hz corner is defined by only one zero. The test time to measure 0.1Hz to 10Hz noise should not exceed ten seconds, as this time limit acts as an additional zero to eliminate noise contributions from the frequency band below 0.1Hz.

Measuring the typical 60nV peak-to-peak noise performance of the LT1007/LT1037 requires special test precautions:

1. The device should be warmed up for at least five minutes. As the op amp warms up, its offset voltage changes typically 3 $\mu$ V due to its chip temperature increasing 10°C to 20°C from the moment the power supplies are turned on. In the ten-second measurement interval these temperature-induced effects can easily exceed tens of nanovolts.
2. For similar reasons, the device must be well shielded from air currents to eliminate the possibility of thermo-

electric effects in excess of a few nanovolts, which would invalidate the measurements.

3. Sudden motion in the vicinity of the device can also "feedthrough" to increase the observed noise.

A noise voltage density test is recommended when measuring noise on a large number of units. A 10Hz noise voltage density measurement will correlate well with a 0.1Hz to 10Hz peak-to-peak noise reading since both results are determined by the white noise and the location of the 1/f corner frequency.

Current noise is measured in the circuit shown in Figure 6 and calculated by the following formula:

$$i_n = \frac{\left[ (e_{no})^2 - (130nV \cdot 101)^2 \right]^{1/2}}{(1M\Omega)(101)}$$

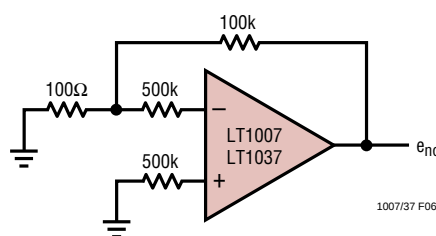


Figure 6

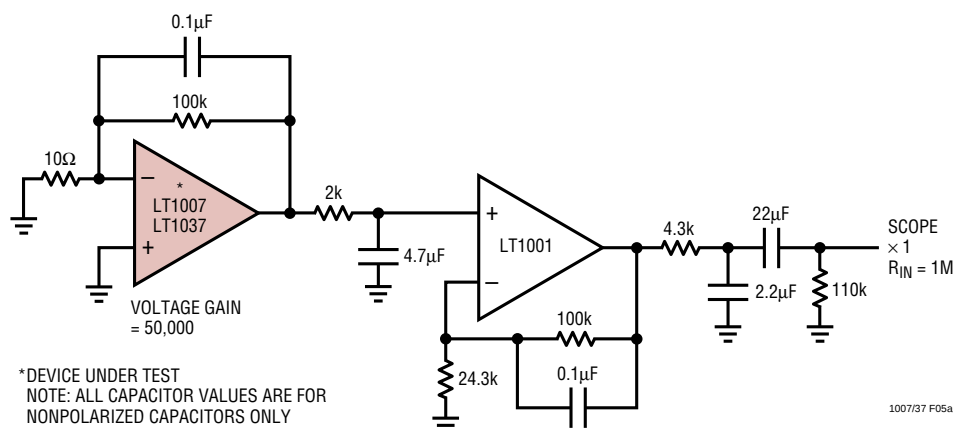


Figure 5a. 0.1Hz to 10Hz Noise Test Circuit

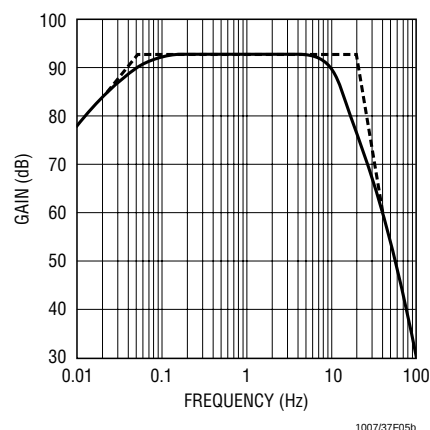


Figure 5b. 0.1Hz to 10Hz Peak-to-Peak Noise Tester Frequency Response

## APPLICATIONS INFORMATION

The LT1007/LT1037 achieve their low noise, in part, by operating the input stage at  $120\mu\text{A}$  versus the typical  $10\mu\text{A}$  of most other op amps. Voltage noise is inversely proportional while current noise is directly proportional to the square root of the input stage current. Therefore, the LT1007/LT1037's current noise will be relatively high. At low frequencies, the low  $1/f$  current noise corner frequency ( $\approx 120\text{Hz}$ ) minimizes current noise to some extent.

In most practical applications, however, current noise will not limit system performance. This is illustrated in the Total Noise vs Source Resistance plot in the Typical Performance Characteristics section, where:

$$\text{Total Noise} = [(\text{voltage noise})^2 + (\text{current noise} \cdot R_S)^2 + (\text{resistor noise})^2]^{1/2}$$

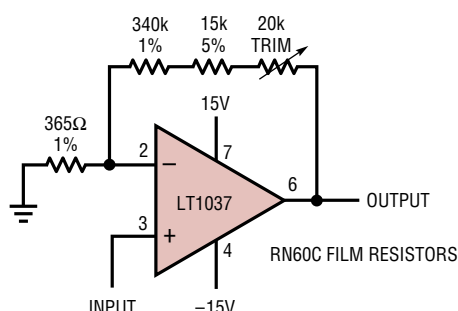
Three regions can be identified as a function of source resistance:

- (i)  $R_S \leq 400\Omega$ . Voltage noise dominates
- (ii)  $400\Omega \leq R_S \leq 50\text{k}$  at  $1\text{kHz}$  } Resistor noise dominates
- $400\Omega \leq R_S \leq 8\text{k}$  at  $10\text{Hz}$  }
- (iii)  $R_S > 50\text{k}$  at  $1\text{kHz}$  } Current noise dominates
- $R_S > 8\text{k}$  at  $10\text{Hz}$  }

Clearly the LT1007/LT1037 should not be used in region (iii), where total system noise is at least six times higher than the voltage noise of the op amp, i.e., the low voltage noise specification is completely wasted.

## TYPICAL APPLICATIONS

Gain 1000 Amplifier with 0.01% Accuracy, DC to 5Hz



THE HIGH GAIN AND WIDE BANDWIDTH OF THE LT1037 (AND LT1007) IS USEFUL IN LOW FREQUENCY, HIGH CLOSED-LOOP GAIN AMPLIFIER APPLICATIONS. A TYPICAL PRECISION OP AMP MAY HAVE AN OPEN-LOOP GAIN OF ONE MILLION WITH 500kHz BANDWIDTH. AS THE GAIN ERROR PLOT SHOWS, THIS DEVICE IS CAPABLE OF 0.1% AMPLIFYING ACCURACY UP TO 0.3Hz ONLY. EVEN INSTRUMENTATION RANGE SIGNALS CAN VARY AT A FASTER RATE. THE LT1037'S "GAIN PRECISION-BANDWIDTH PRODUCT" IS 200 TIMES HIGHER AS SHOWN.

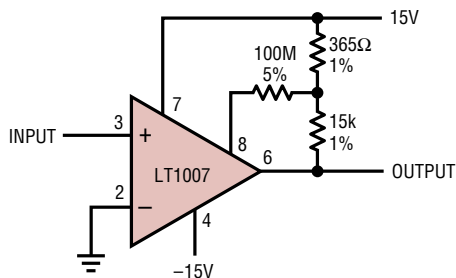
Gain Error vs Frequency  
Closed-Loop Gain = 1000



1007/37 TA03

## TYPICAL APPLICATIONS

### Microvolt Comparator with Hysteresis

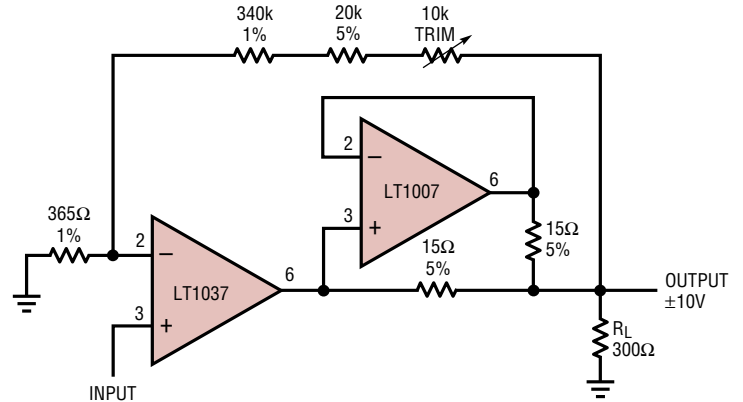


POSITIVE FEEDBACK TO ONE OF THE NULLING TERMINALS CREATES APPROXIMATELY  $5\mu\text{V}$  OF HYSTERESIS. OUTPUT CAN SINK  $16\text{mA}$ .

INPUT OFFSET VOLTAGE IS TYPICALLY CHANGED LESS THAN  $5\mu\text{V}$  DUE TO THE FEEDBACK.

1007/37 TA04

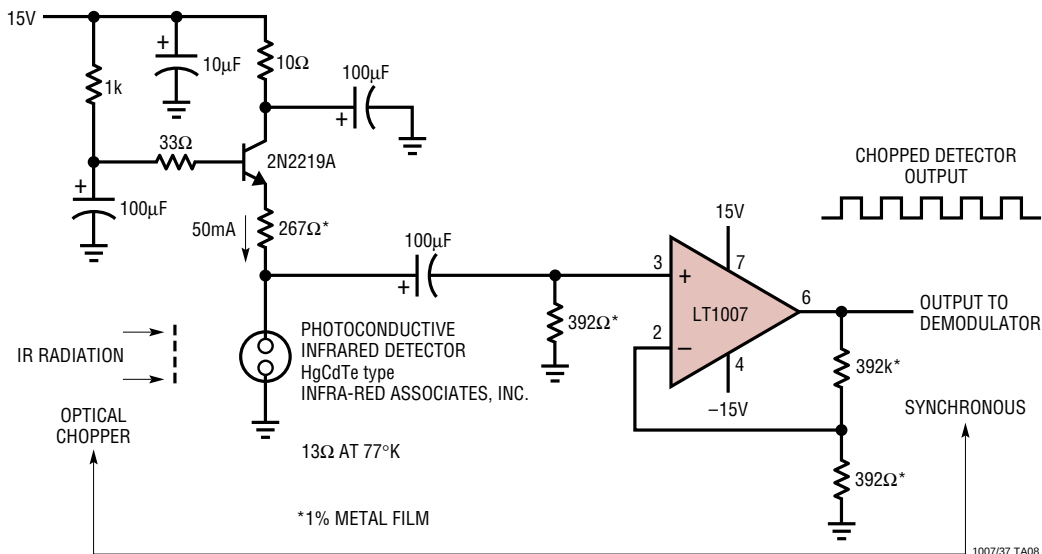
### Precision Amplifier Drives $300\Omega$ Load to $\pm 10\text{V}$



THE ADDITION OF THE LT1007 DOUBLES THE AMPLIFIER'S OUTPUT DRIVE TO  $\pm 33\text{mA}$ . GAIN ACCURACY IS  $0.02\%$ , SLIGHTLY DEGRADED COMPARED TO ABOVE BECAUSE OF SELF-HEATING OF THE LT1037 UNDER LOAD.

1007/37 TA05

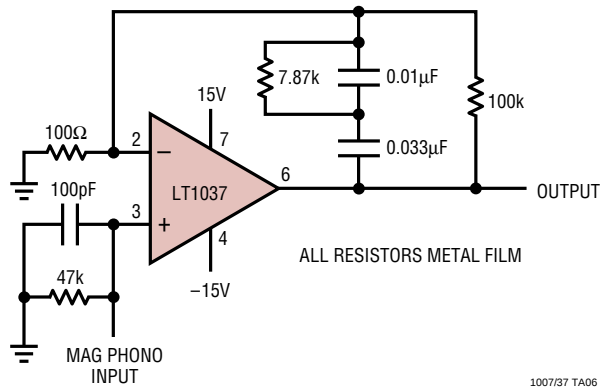
### Infrared Detector Preamplifier



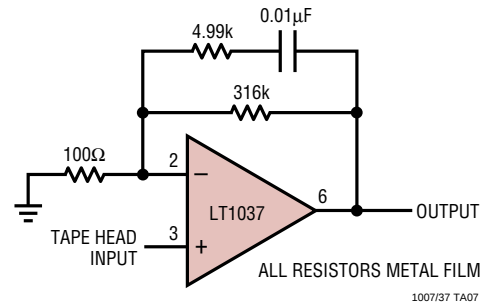
1007/37 TA08

## TYPICAL APPLICATIONS

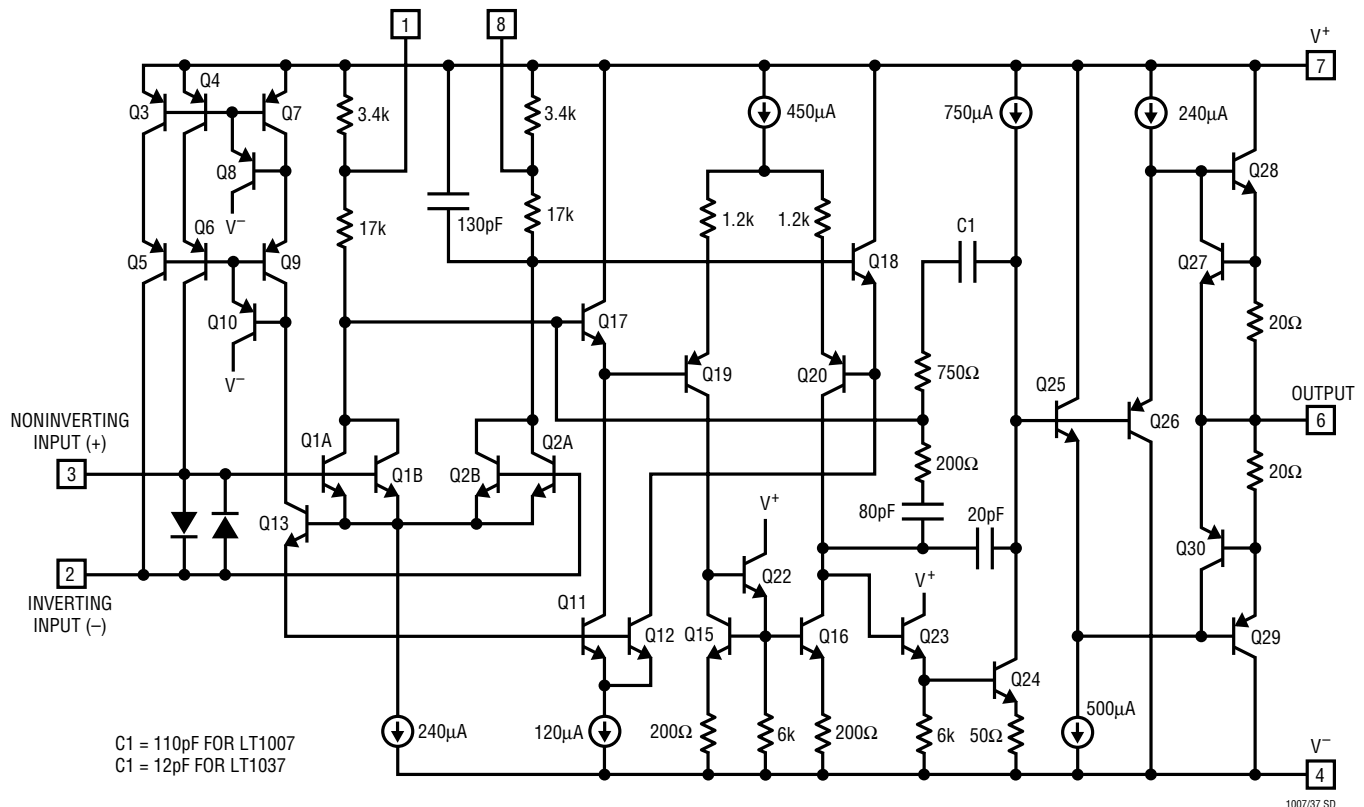
Phono Preamplifier



Tape Head Amplifier



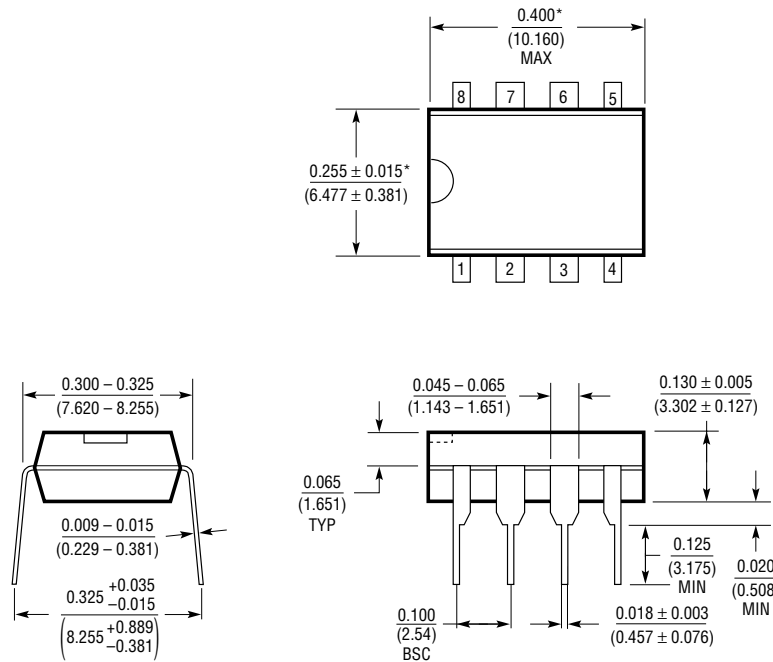
## SIMPLIFIED SCHEMATIC





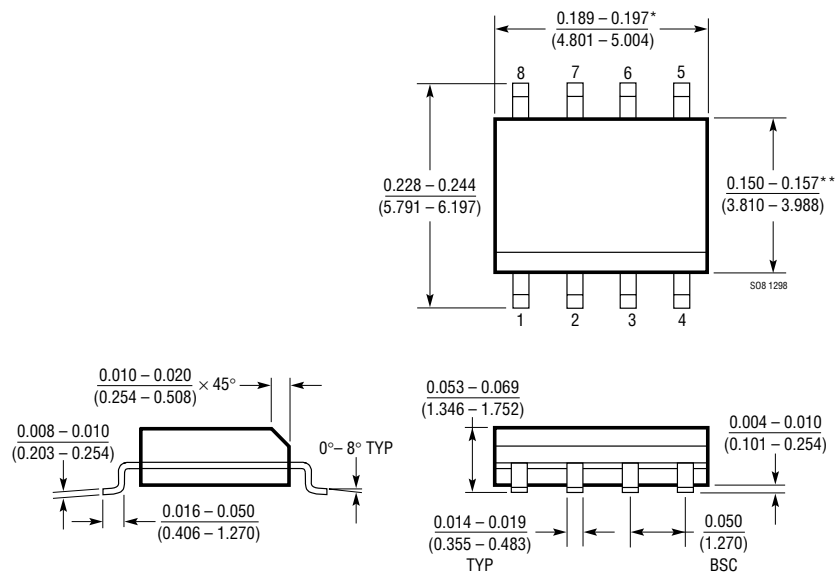
# PACKAGE DESCRIPTION

## N8 Package 8-Lead PDIP (Narrow .300 Inch) (Reference LTC DWG # 05-08-1510)



\*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.  
MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.010 INCH (0.254mm)

## S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)



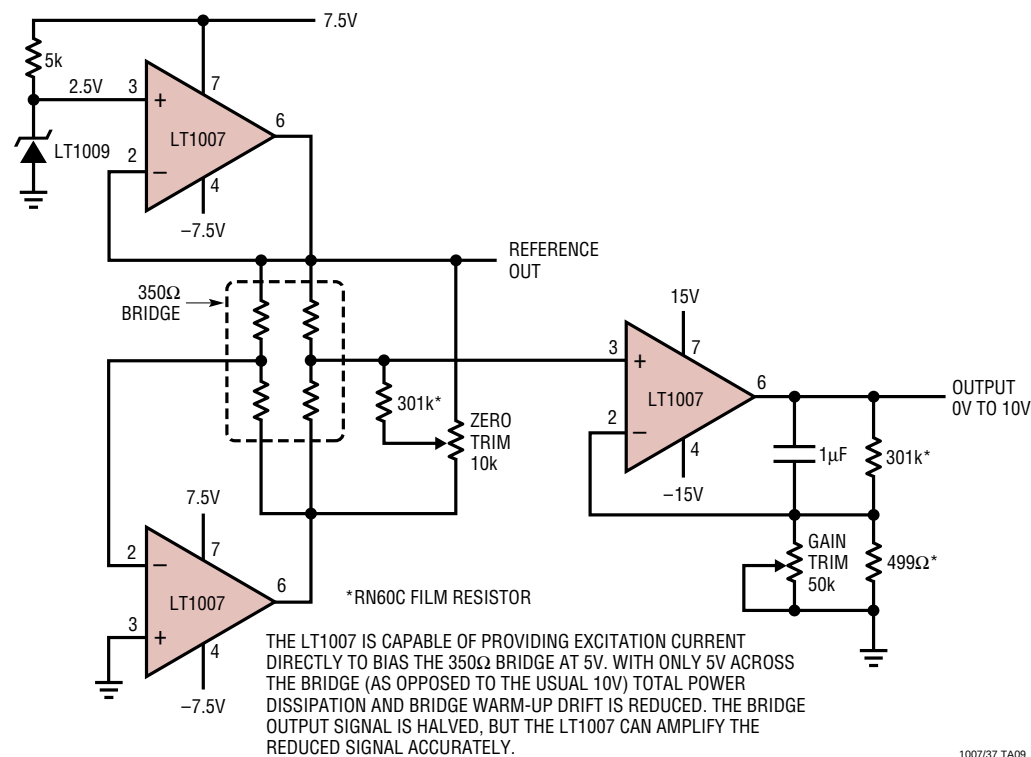
\*DIMENSION DOES NOT INCLUDE MOLD FLASH. MOLD FLASH  
SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE

\*\*DIMENSION DOES NOT INCLUDE INTERLEAD FLASH. INTERLEAD  
FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE

sn100737 100737fbs

TYPICAL APPLICATION

Strain Gauge Signal Conditioner with Bridge Excitation



RELATED PARTS

| PART NUMBER   | DESCRIPTION                                                                     | COMMENTS                        |
|---------------|---------------------------------------------------------------------------------|---------------------------------|
| LT1028        | Ultralow Noise Precision Op Amp                                                 | Lowest Noise 0.85nV/√Hz         |
| LT1115        | Ultralow Noise, Low distortion Audio Op Amp                                     | 0.002% THD, Max Noise 1.2mV/√Hz |
| LT1124/LT1125 | Dual/Quad Low Noise, High Speed Precision Op Amps                               | Similar to LT1007               |
| LT1126/LT1127 | Dual/Quad Decompensated Low Noise, High Speed Precision Op Amps                 | Similar to LT1037               |
| LT1498/LT1499 | 10MHz, 5V/μs, Dual/Quad Rail-to-Rail Input and Output Precision C-Load™ Op Amps |                                 |

C-Load is a trademark of Linear Technology Corporation.

## Данный компонент на территории Российской Федерации

**Вы можете приобрести в компании MosChip.**

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9